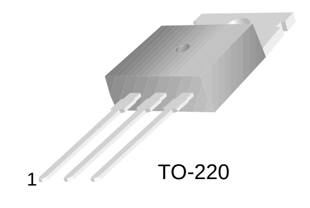


KSC5027

High Voltage and High Reliability

- High Speed Switching
- Wide SOA



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	1100	V
V_{CEO}	Collector-Emitter Voltage	800	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	3	A
I_{CP}	Collector Current (Pulse)	10	A
I_B	Base Current	1.5	A
P_C	Collector Dissipation (T_C=25°C)	50	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 1mA, I_E = 0	1100			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 5mA, R_{BE} =∞	800			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E = 1mA, I_C = 0	7			V
V_{CEX}(sus)	Collector-Emitter Sustaining Voltage	I_C = 1.5A, I_{B1} = -I_{B2} = 0.3A L = 2mH, Clamped	800			V
I_{CBO}	Collector Cut-off Current	V_{CB} = 800V, I_E = 0			10	µA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0			10	µA
h_{FE1} h_{FE2}	DC Current Gain	V_{CE} = 5V, I_C = 0.2A V_{CE} = 5V, I_C = 1A	10 8		40	
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 1.5A, I_B = 0.3A			2	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 1.5A, I_B = 0.3A			1.5	V
C_{ob}	Output Capacitance	V_{CB} = 10V, I_E = 0, f = 1MHz		60		pF
f_T	Current Gain Bandwidth Product	V_{CE} = 10V, I_C = 0.2A		15		MHz
t_{ON}	Turn ON Time	V_{CC} = 400V I_C = 5I_{B1} = -2.5I_{B2} = 2A R_L = 200Ω			0.5	µs
t_{STG}	Storage Time				3	µs
t_F	Fall Time				0.3	µs

h_{FE} Classification

Classification	N	R	O
h_{FE1}	10 ~ 20	15 ~ 30	20 ~ 40

Typical Characteristics

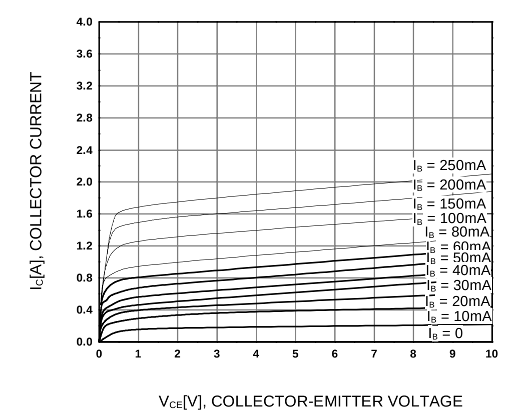


Figure 1. Static Characteristic



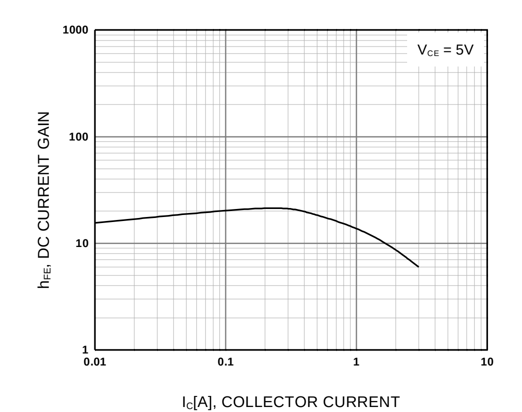


Figure 2. DC current Gain

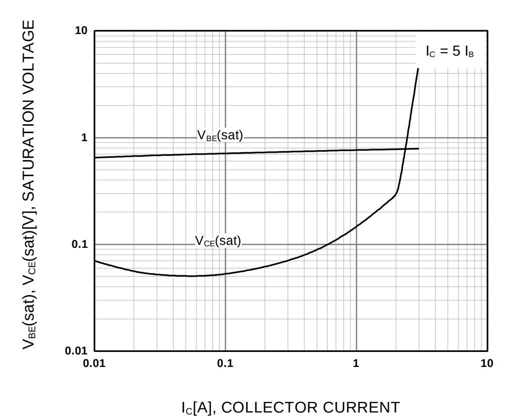


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

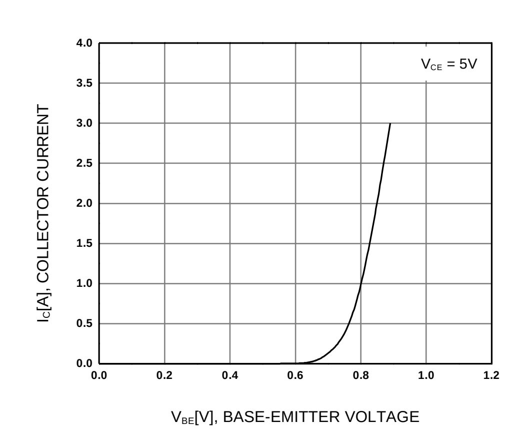


Figure 4. Base-Emitter On Voltage

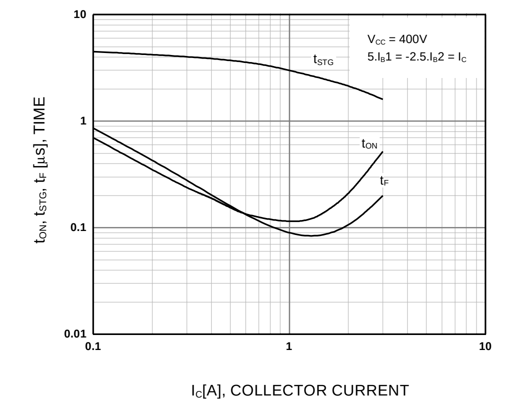


Figure 5. Switching Time

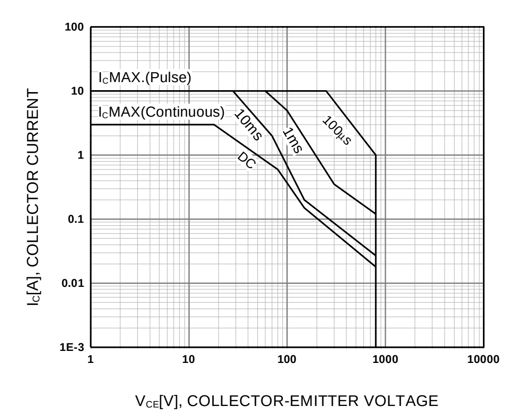


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

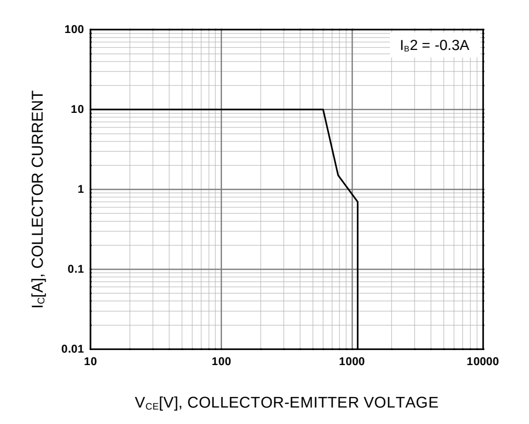


Figure 7. Reverse Bias Operating Area

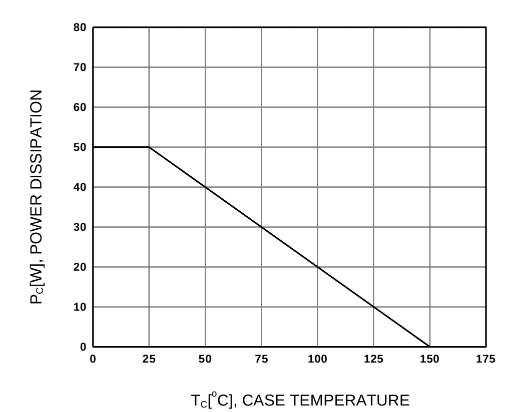
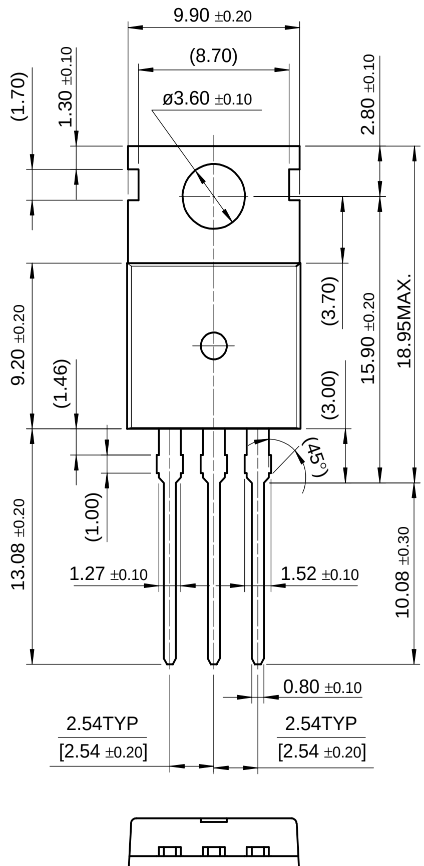
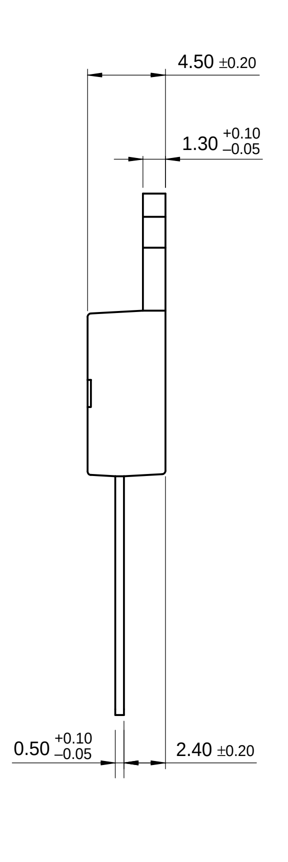


Figure 8. Power Derating

Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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